NSN 5962-01-121-0558



Memory Microcircuit - Page 1 of 1 View Online at https://aerobasegroup.com/nsn/5962-01-121-0558 **Body Length:** Between 1.240 inches and 1.255 inches **Body Width:** Between 0.545 inches and 0.555 inches **Body Height:** Between 0.145 inches and 0.155 inches **Maximum Power Dissipation Rating:** 1.0 watts **Operating Tempurature Range:** -0.0/+70.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **End Application:** 4920-01-065-4907 81205 **Features Provided:** Monolithic and positive outputs and 3-state output and w/clock and programmable **Inclosure Material:** Plastic **Inclosure Configuration:** Dual-in-line **Output Logic Form:** N-type metal oxide-semiconductor logic **Input Circuit Pattern:** 14 input **Terminal Surface Treatment:** Solder Voltage Rating And Type Per Characteristic: 6.5 volts power source **Time Rating Per Chacteristic:** 450.00 nanoseconds propagation delay time, low to high level output and 450.00 nanoseconds propagation delay time, high to low level output **Memory Device Type:** Rom **Terminal Type And Quantity:**

24 printed circuit

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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